

54AC/74AC821 • 54ACT/74ACT821 10-Bit D Flip-Flop with TRI-STATE® Outputs

General Description

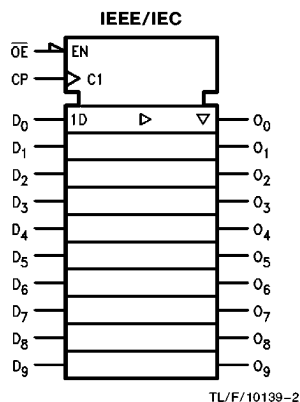
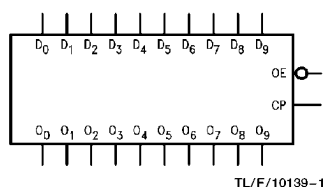
The 'AC/'ACT821 is a 10-bit D flip-flop with TRI-STATE outputs arranged in a broadside pinout.

The 'AC/'ACT821 is functionally identical to the AM29821.

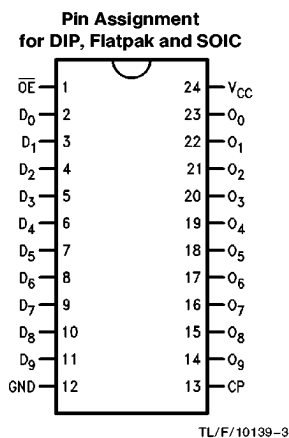
Features

- TRI-STATE outputs for bus interfacing
- Noninverting outputs
- Outputs source/sink 24 mA
- 'ACT821 has TTL-compatible inputs
- Standard Military Drawing (SMD)
 - 'ACT821: 5962-88705

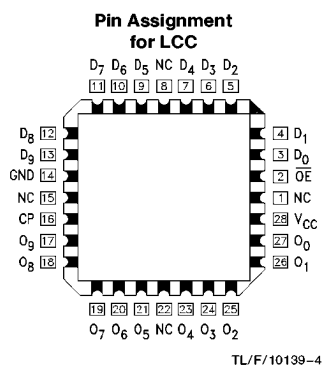
Logic Symbols



Connection Diagrams



Pin Names	Description
D ₀ –D ₉	Data Inputs
O ₀ –O ₉	Data Outputs
$\overline{OE}$	Output Enable Input
CP	Clock Input



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Functional Description

The 'AC/'ACT821 consists of ten D-type edge-triggered flip-flops. The buffered Clock (CP) and buffered Output Enable ($\overline{OE}$) are common to all flip-flops. The flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH CP transition. With $\overline{OE}$ LOW the contents of the flip-flops are available at

the outputs. When $\overline{OE}$ is HIGH the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

The 'AC/'ACT821 is functionally and pin compatible with the AM29821.

Function Table

Inputs			Internal	Outputs	Function
$\overline{OE}$	CP	D	Q	O	
H	—	L	L	Z	High Z
H	—	H	H	Z	High Z
L	—	L	L	L	Load
L	—	H	H	H	Load

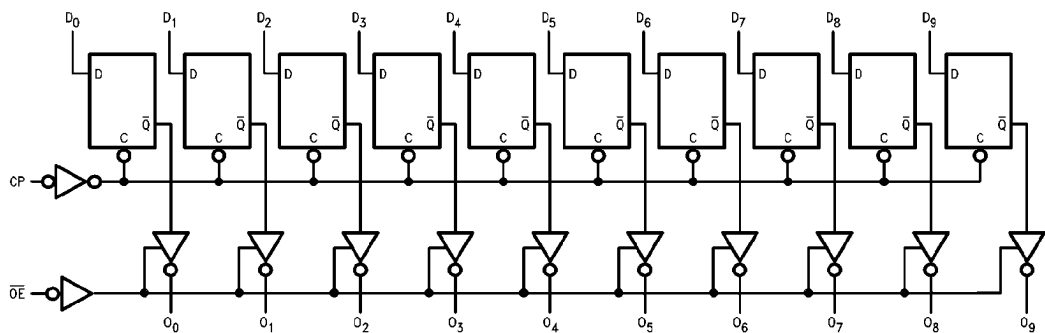
H = HIGH Voltage Level

L = LOW Voltage Level

Z = HIGH Impedance

— = LOW-to-HIGH Clock Transition

Logic Diagram



TL/F/10139-5

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Rating (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
$V_I = -0.5V$	−20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V_I)	−0.5V to $V_{CC} + 0.5V$
DC Output Diode Current (I_{OK})	
$V_O = -0.5V$	−20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O)	−0.5V to $V_{CC} + 0.5V$
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
CDIP	175°C
PDIP	140°C

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT™ circuits outside databook specifications.

Recommended Operating Conditions

Supply Voltage (V_{CC})	
'AC	2.0V to 6.0V
'ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	
74AC/ACT	−40°C to +85°C
54AC/ACT	−55°C to +125°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
'AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
'ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

DC Characteristics for 'AC Family Devices

Symbol	Parameter	V _{CC} (V)	74AC		54AC	74AC	Units	Conditions
			T _A = +25°C		T _A = −55°C to +125°C	T _A = −40°C to +85°C		
			Typ	Guaranteed Limits				
V _{IH}	Minimum High Level Input Voltage	3.0	1.5	2.1	2.1	2.1	V	V _{OUT} = 0.1V or V _{CC} − 0.1V
		4.5	2.25	3.15	3.15	3.15		
		5.5	2.75	3.85	3.85	3.85		
V _{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.9	0.9	0.9	V	V _{OUT} = 0.1V or V _{CC} − 0.1V
		4.5	2.25	1.35	1.35	1.35		
		5.5	2.75	1.65	1.65	1.65		
V _{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	2.9	V	I _{OUT} = −50 μA
		4.5	4.49	4.4	4.4	4.4		
		5.5	5.49	5.4	5.4	5.4		
		3.0		2.56	2.4	2.46	V	*V _{IN} = V _{IL} or V _{IH} −12 mA I _{OH} −24 mA −24 mA
		4.5		3.86	3.7	3.76		
		5.5		4.86	4.7	4.76		
V _{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	0.1	V	I _{OUT} = 50 μA
		4.5	0.001	0.1	0.1	0.1		
		5.5	0.001	0.1	0.1	0.1		
		3.0		0.36	0.50	0.44	V	*V _{IN} = V _{IL} or V _{IH} 12 mA I _{OL} 24 mA 24 mA
		4.5		0.36	0.50	0.44		
		5.5		0.36	0.50	0.44		
I _{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	±1.0	μA	V _I = V _{CC} , GND

*All outputs loaded; thresholds on input associated with output under test.

DC Characteristics for 'AC Family Devices (Continued)

Symbol	Parameter	V _{CC} (V)	74AC		54AC	74AC	Units	Conditions
			T _A = +25°C		T _A = −55°C to +125°C	T _A = −40°C to +85°C		
			Typ	Guaranteed Limits				
I _{OZ}	Maximum TRI-STATE® Current	5.5		±0.5	±10.0	±5.0	μA	V _I (OE) = V _{IL} , V _{IH} V _I = V _{CC} , GND V _O = V _{CC} , GND
I _{OLD}	†Minimum Dynamic Output Current	5.5			50	75	mA	V _{OLD} = 1.65V Max
I _{OHD}		5.5			−50	−75	mA	V _{OHD} = 3.85V Min
I _{CC}	Maximum Quiescent Supply Current	5.5		8.0	160.0	80.0	μA	V _{IN} = V _{CC} or GND

†Maximum test duration 2.0 ms, one output loaded at a time.

Note: I_{IH} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

I_{CC} for 54AC @ 25°C is identical to 74AC @ 25°C.

DC Characteristics for 'ACT Family Devices

Symbol	Parameter	V _{CC} (V)	74ACT		54ACT		74ACT		Units	Conditions
			T _A = +25°C		T _A = −55°C to +125°C		T _A = −40°C to +85°C			
			Typ	Guaranteed Limits						
V _{IH}	Minimum High Level Input Voltage	4.5	1.5	2.0	2.0	2.0	2.0	2.0	V	V _{OUT} = 0.1V or V _{CC} − 0.1V
		5.5	1.5	2.0	2.0	2.0	2.0	2.0		
V _{IL}	Maximum Low Level Input Voltage	4.5	1.5	0.8	0.8	0.8	0.8	0.8	V	V _{OUT} = 0.1V or V _{CC} − 0.1V
		5.5	1.5	0.8	0.8	0.8	0.8	0.8		
V _{OH}	Minimum High Level Output Voltage	4.5	4.49	4.4	4.4	4.4	4.4	4.4	V	I _{OUT} = −50 μA
		5.5	5.49	5.4	5.4	5.4	5.4	5.4		
		4.5		3.86	3.70	3.76	V	*V _{IN} = V _{IL} or V _{IH} −24 mA I _{OH} −24 mA		
		5.5		4.86	4.70	4.76			4.76	
V _{OL}	Maximum Low Level Output Voltage	4.5	0.001	0.1	0.1	0.1	0.1	0.1	V	I _{OUT} = 50 μA
		5.5	0.001	0.1	0.1	0.1	0.1	0.1		
		4.5		0.36	0.50	0.44	V	*V _{IN} = V _{IL} or V _{IH} 24 mA I _{OL} 24 mA		
		5.5		0.36	0.50	0.44			0.44	
I _{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	±1.0	±1.0	μA	V _I = V _{CC} , GND	
I _{OZ}	Maximum TRI-STATE® Current	5.5		±0.5	±10.0	±5.0	±5.0	μA	V _I = V _{IL} , V _{IH} V _O = V _{CC} , GND	
I _{CCT}	Maximum I _{CC} /Input	5.5	0.6		1.6	1.5	1.5	1.5	mA	V _I = V _{CC} − 2.1V
I _{OLD}	†Minimum Dynamic Output Current	5.5			50	75	75	75	mA	V _{OLD} = 1.65V Max
I _{OHD}		5.5			−50	−75	−75	−75	mA	V _{OHD} = 3.85V Min
I _{CC}	Maximum Quiescent Supply Current	5.5		8.0	160.0	80.0	80.0	80.0	μA	V _{IN} = V _{CC} or GND

*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time.

Note: I_{CC} for 54ACT @ 25°C is identical to 74ACT @ 25°C.

AC Electrical Characteristics

Symbol	Parameter	V _{CC} * (V)	74AC			54AC		74AC		Units
			T _A = +25°C C _L = 50 pF			T _A = −55°C to +125°C C _L = 50 pF		T _A = −40°C to +85°C C _L = 50 pF		
			Min	Typ	Max	Min	Max	Min	Max	
t _{max}	Maximum Clock Frequency	3.3 5.0	110 120	145 160		95 100		100 110		MHz
t _{PLH}	Propagation Delay CP to O _n	3.3 5.0	3.0 2.0	8.0 6.0	13.0 9.5	1.0 1.5	13.0 9.5	3.0 2.0	15.0 10.5	ns
t _{PHL}	Propagation Delay CP to O _n	3.3 5.0	3.0 2.0	8.0 5.5	13.0 9.5	1.0 1.5	13.0 9.5	3.0 2.0	15.0 10.5	ns
t _{PZH}	Output Enable Time OE to O _n	3.3 5.0	2.5 1.5	6.0 4.5	11.0 8.0	1.0 1.5	13.0 9.5	2.5 1.5	12.0 9.0	ns
t _{PZL}	Output Enable Time OE to O _n	3.3 5.0	2.5 1.5	6.5 5.0	11.0 8.0	1.0 1.5	13.0 9.5	2.5 1.5	12.0 9.0	ns
t _{PHZ}	Output Disable Time OE to O _n	3.3 5.0	2.5 1.5	6.5 5.0	10.5 8.0	1.0 1.5	12.0 10.0	2.5 1.5	11.0 8.5	ns
t _{PLZ}	Output Disable Time OE to O _n	3.3 5.0	2.5 1.5	6.0 4.5	10.5 8.0	1.0 1.5	12.0 10.0	2.5 1.5	11.0 8.5	ns

*Voltage Range 3.3 is 3.3V ±0.3V
Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements

Symbol	Parameter	V _{CC} * (V)	74AC		54AC	74AC	Units
			T _A = +25°C C _L = 50 pF		T _A = −55°C to +125°C C _L = 50 pF	T _A = −40°C to +85°C C _L = 50 pF	
			Typ	Guaranteed Minimum			
t _s	Setup Time, HIGH or LOW D _n to CP	3.3	−1.0	1.5	3.0	1.5	ns
		5.0	−1.0	1.5	3.0	1.5	
t _h	Hold Time, HIGH or LOW D _n to CP	3.3	−1.0	3.5	3.0	4.0	ns
		5.0	−1.0	3.5	3.0	4.0	
t _w	CP Pulse Width HIGH or LOW	3.3	3.5	5.0	6.0	5.5	ns
		5.0	2.5	4.0	5.0	4.0	

*Voltage Range 3.3 is 3.3V ±0.3V
Voltage Range 5.0 is 5.0V ±0.5V

AC Electrical Characteristics

Symbol	Parameter	V _{CC} * (V)	74ACT			54ACT		74ACT		Units
			T _A = +25°C C _L = 50 pF			T _A = −55°C to +125°C C _L = 50 pF		T _A = −40°C to +85°C C _L = 50 pF		
			Min	Typ	Max	Min	Max	Min	Max	
f _{max}	Maximum Clock Frequency	5.0	120	150		85		110		MHz
t _{PLH}	Propagation Delay CP to O _n	5.0	2.0	6.0	9.5	1.5	11.5	1.5	10.5	ns
t _{PHL}	Propagation Delay CP to O _n	5.0	2.5	6.0	9.5	1.5	11.5	2.0	10.5	ns
t _{PZH}	Output Enable Time OE to O _n	5.0	2.5	7.0	10.5	1.5	12.5	2.0	11.5	ns
t _{PZL}	Output Enable Time OE to O _n	5.0	2.5	7.0	10.5	1.5	13.0	2.0	12.0	ns
t _{PHZ}	Output Disable Time OE to O _n	5.0	1.5	7.5	12.0	1.5	13.5	1.0	13.0	ns
t _{PLZ}	Output Disable Time OE to O _n	5.0	1.5	7.0	10.5	1.5	12.5	1.0	11.5	ns

*Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements

Symbol	Parameter	V _{CC} * (V)	74ACT		54ACT	74ACT	Units
			T _A = +25°C C _L = 50 pF		T _A = -55°C to +125°C C _L = 50 pF	T _A = -40°C to +85°C C _L = 50 pF	
			Typ	Guaranteed Minimum			
t _s	Setup Time, HIGH or LOW D _n to CP	5.0	2.5	2.0	4.0	2.5	ns
t _h	Hold Time, HIGH or LOW D _n to CP	5.0	-0.5	2.0	3.0	2.5	ns
t _w	CP Pulse Width HIGH or LOW	5.0	3.0	4.5	6.0	5.5	ns

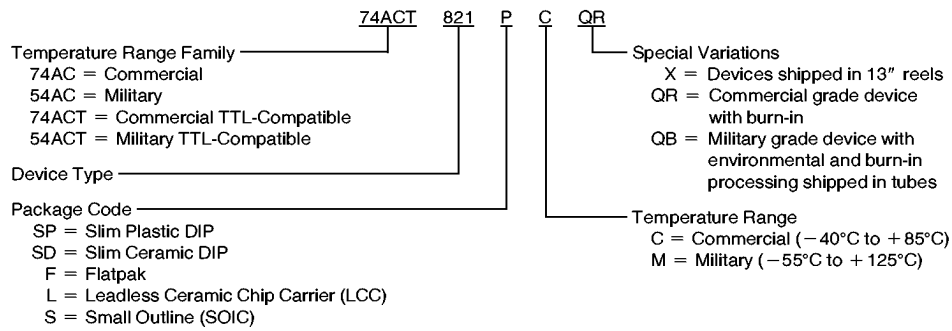
*Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

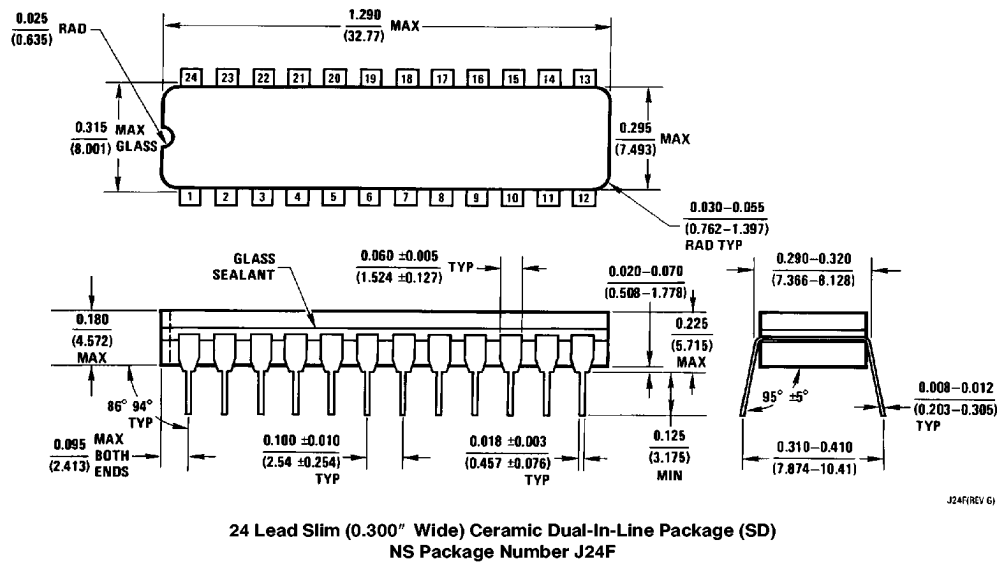
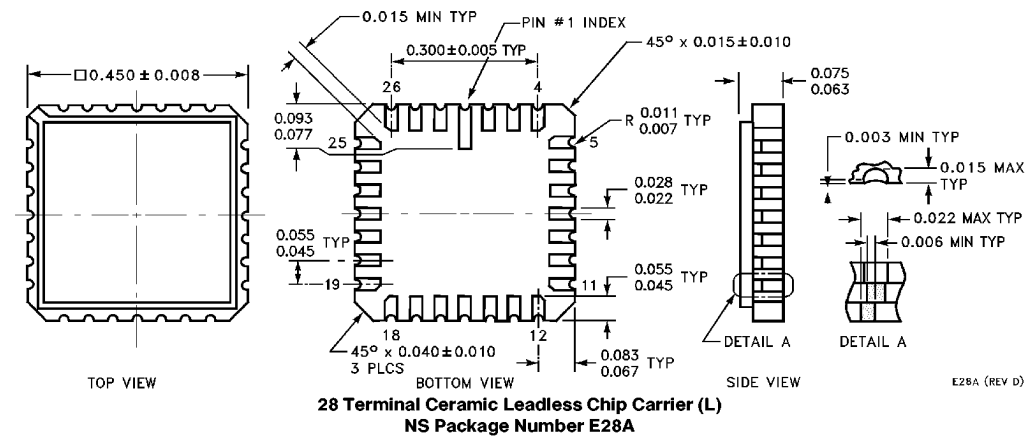
Symbol	Parameter	Typ	Units	Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = OPEN
C _{PD}	Power Dissipation Capacitance	35.0	pF	V _{CC} = 5.0V

Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



Physical Dimensions inches (millimeters)



Physical Dimensions inches (millimeters) (Continued)

24 Lead Small Outline Integrated Circuit (S)
NS Package Number M24B

0.6141
0.5985
15.60
15.20

0.4190
0.3940
10.65
10.00

0.2992
0.2914
7.6
7.4

0.050
1.27

0.0200
0.0138
0.508
0.350

0.1043
0.0926
2.65
2.35

0.014
0.35

0.0118
0.0040
0.3
0.1

0.0125
0.0091
0.32
0.23

45° x 0.029
0.010
0.75
0.25

8° MAX TYP - ALL LEADS

0.0500
0.0160
1.27
0.40

ALL LEAD TIPS

M24B (REV F)

24 Lead Slim (0.300" Wide) Plastic Dual-In-Line Package (SP)
NS Package Number N24C

1.243 - 1.270
(31.97 - 32.26)
MAX

0.092
(2.337)
(2 PLS)

0.032
(0.813)
RAD

0.062
(1.575)
RAD

0.260 ± 0.003
(6.604 ± 0.127)

0.300 - 0.320
(7.62 - 8.128)

0.009 - 0.015
(0.229 - 0.381)

95° ± 5°

0.280
(7.112)
MIN

0.325 ± 0.040
- 0.015
(8.255 ± 1.016)
(0.255 - 0.381)

0.040
(1.016)
TYP

0.130 ± 0.005
(3.302 ± 0.127)

0.020
(0.508)
MIN

0.145 - 0.200
(3.683 - 5.080)

0.018 ± 0.003
(0.457 ± 0.076)
TYP

0.100 ± 0.010
(2.54 ± 0.254)
TYP

0.075 ± 0.015
(1.905 ± 0.381)

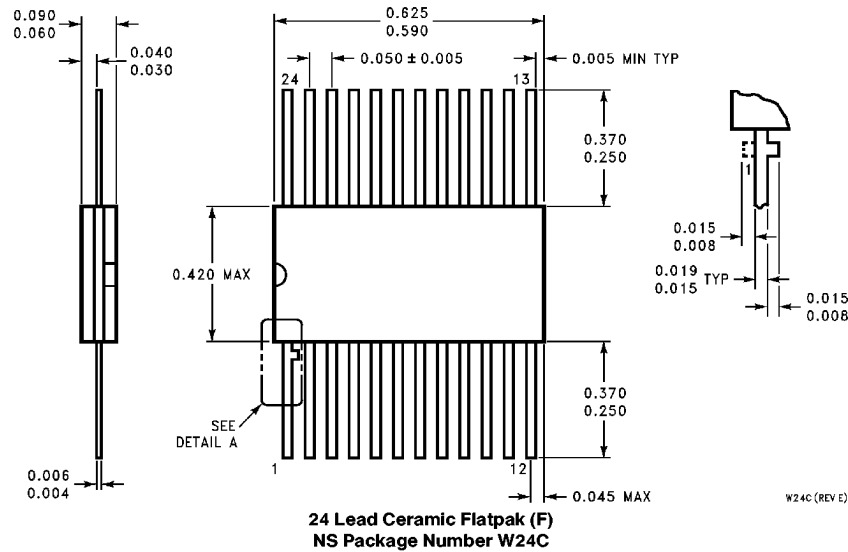
0.065
(1.651)

0.125 - 0.145
(3.175 - 3.556)
MIN

90° ± 4° TYP

N24C (REV F)

Physical Dimensions inches (millimeters) (Continued)



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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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